

# SOT-227 AC Switch Full Controlled Thyristor Power Module, 60 A, 1600 V



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PRIMARY CHARACTERISTICS				
V <sub>RRM</sub> / V <sub>DRM</sub>	1600 V			
V <sub>TM</sub> (typical) at 60 A, 25 °C	1.2 V			
I <sub>T(AV)</sub> , T <sub>C</sub> = 110 °C	60 A			
T <sub>VJ</sub>	150 °C			
T <sub>operative</sub>	125 °C			
Package	SOT-227			
Circuit	Two thyristors, back to back			

#### **FEATURES**

- · High voltage
- Industrial standard package
- Low thermal resistance
- UL pending
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **BENEFITS**

- Excellent thermal performances
- · High surge capability
- Easy mounting on heatsink
- Thyristor for line frequency

## **APPLICATIONS**

Line rectifying 50 Hz / 60 Hz

- Softstart AC motor control
- DC motor control
- Power converter
- AC power control
- Lighting and temperature control

MAJOR RATINGS AND CHARACTERISTICS (T <sub>J</sub> max. 150 °C)						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>T(AV)</sub>	110 °C	60				
<b>1</b>	50 Hz	850	А			
I <sub>TSM</sub>	60 Hz	890				
l <sup>2</sup> t	50 Hz	3.6	kA <sup>2</sup> s			
	60 Hz	3.3	KA-S			
I²√t		36.1	kA²√s			
V <sub>RRM</sub> / V <sub>DRM</sub>		1600	V			
T <sub>op</sub>	Operating temperature	-40 to +125				
T <sub>Stg</sub>		-40 to +150	°C			
TJ	Virtual junction temperature	-40 to +150				

## **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I <sub>RRM,</sub> I <sub>DRM</sub> AT 125 °C mA			
1600	1700	1600	25			



ON-STATE CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current (thyristors)	I <sub>T(AV)</sub>	180° conduction, h	alf sine wave, To	; = 110 °C	60	
		t = 10 ms	No voltage	0	850	А
Maximum peak, one-cycle non-repetitive	, [	t = 8.3 ms	reapplied	Sinusoidal half wave,	890	
on-state	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	initial T <sub>J</sub> = 150 °C	715	
		t = 8.3 ms	reapplied		748	
		t = 10 ms	No voltage		3.6	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 8.3 ms	reapplied	Initial T <sub>.1</sub> = 150 °C	3.3	kA <sup>2</sup> s
Wiaximum i-t for fusing	I-I	t = 10 ms	100 % V <sub>RRM</sub>		2.5	
		t = 8.3 ms	reapplied		2.3	
Maximum l²√t for fusing	I <sup>2</sup> √t <sup>(1)</sup>	t = 0.1 ms to 10 ms, no voltage reapplied			36.1	kA²√s
Wiaximum 1 Verol lusing		$T_J = T_J$ maximum				
Maximum value or threshold voltage	V <sub>T(TO)</sub> (2)	Low level (3)	T <sub>J</sub> = 150 °C		0.89	· V
Waximum value of threshold voltage		High level <sup>(4)</sup>			1.02	
Maximum value of on-state slope resistance	r <sub>t</sub> (2)	Low level (3)	T <sub>J</sub> = 150 °C		9.17	mΩ
Waximum value of on state slope resistance	'[ '	High level <sup>(4)</sup>			9.01	
Maximum peak on-state voltage	V <sub>TM</sub>	I <sub>TM</sub> = 60 A	T <sub>J</sub> = 25 °C		1.50	V
Waximum peak on state voltage	VIM	$T_{J} = 150 ^{\circ}\text{C}$			1.41	v
Maximum non-repetitive rate of rise of	dl/dt	T <sub>J</sub> = 125 °C, I <sub>T</sub> = 100 A, I <sub>qt</sub> = 450 mA, V <sub>GT</sub> = 2.5 V		500	A/µs	
turned on current	GI/GI	1J - 125 O, 1T = 100 M, 1gt = 450 IIIM, VGT = 2.5 V		550	7 ν μο	
Maximum holding current	I <sub>H</sub>	T <sub>J</sub> = 25 °C, anode supply = 6 V, resistive load, gate open circuit		200	mA	
Maximum latching current	ΙL	$T_J = 25$ °C, anode supply = 6 V, resistive load 400		400		

#### Notes

- (1)  $I^2t$  for time  $t_x = I^2\sqrt{t} \ x \ \sqrt{t_x}$
- $^{(2)}$  Average power =  $V_{T(TO)} \; x \; I_{T(AV)} + r_t \; x \; (I_{T(RMS)})^2$
- (3) 16.7 %  $\times \pi \times I_{AV} < I < \pi \times I_{AV}$
- $^{(4)}~I>\pi~x~I_{AV}$

TRIGGERING					
PARAMETER	SYMBOL		TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	$P_{GM}$	10 ms sine p	oulse, no voltage reapplied	10	W
Maximum average gate power	P <sub>G(AV)</sub>			2.5	VV
Maximum peak gate current	I <sub>GM</sub>			2.5	Α
Maximum peak negative gate voltage	-V <sub>GM</sub>			10	
		T <sub>J</sub> = -40 °C		1.6	V
Maximum gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	1.5	V
		T <sub>J</sub> = 150 °C		1	
		T <sub>J</sub> = -40 °C		150	
Maximum gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	100	mA
		T <sub>J</sub> = 150 °C		45	
Maximum gate voltage that will not trigger	$V_{GD}$	T <sub>J</sub> = 150 °C, 67 % V <sub>DRM</sub> applied		0.2	V
Maximum gate current that will not trigger	$I_{GD}$	T <sub>J</sub> = 150 °C, 67 % V <sub>DRM</sub> applied		5	mA

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak reverse and off-state leakage current at V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>RRM,</sub> I <sub>DRM</sub>	T <sub>J</sub> = 125 °C, gate open circuit	25	mA	
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	2500 (1 min)	V	
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = 150$ °C, linear to 0.67 $V_{DRM}$	1000	V/µs	



THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum internal thermal resis	stance,	R <sub>thJC</sub>	DC operation	0.29	°C/W
Typical thermal resistance, case to heat sink per module		R <sub>thCS</sub>	Mounting surface flat, smooth and greased	0.1	C/VV
Mounting torque ± 10 %	to heat sink		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	1.3	Nm
Approximate weight				30	g
Case style				SOT	-227

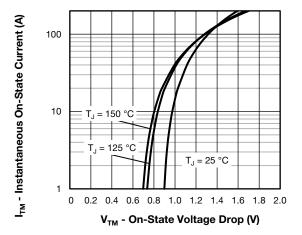


Fig. 1 - I<sub>TM</sub> vs. V<sub>TM</sub> (On-State Voltage Drop Characteristics)

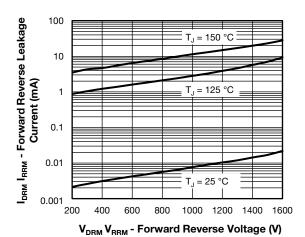


Fig. 2 - I<sub>DRM</sub> I<sub>RRM</sub> vs. V<sub>DRM</sub> V<sub>RRM</sub> (Forward Reverse Leakage Current)

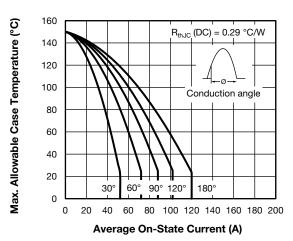


Fig. 3 - Maximum Allowable Case Temperature vs. Average On-State Current (Current Rating Characteristics)

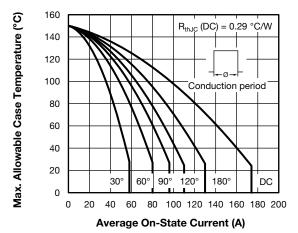


Fig. 4 - Maximum Allowable Case Temperature vs. Average On-State Current (Current Rating Characteristics)

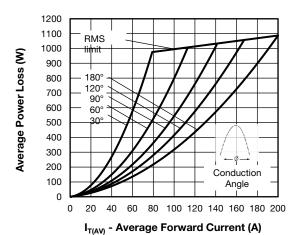


Fig. 5 - Average Power Loss vs. Average Forward Current (Forward Power Loss Characteristics)

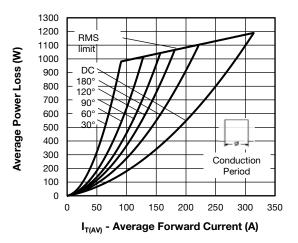


Fig. 6 - Average Power Loss vs. Average Forward Current (Forward Power Loss Characteristics)

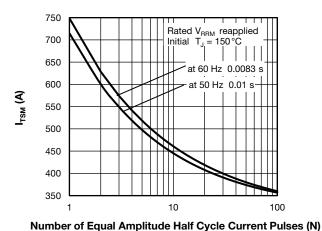
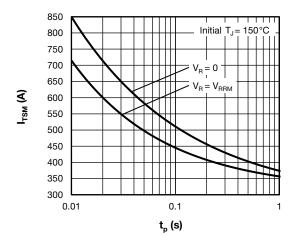


Fig. 7 - I<sub>TSM</sub> vs. N (Non-Repetitive Peak Forward Surge Current vs. Number Pulses)



 $\label{eq:Fig. 8-l} \textit{Fig. 8-l}_{TSM} \, \textit{vs. t}_{p} \\ \text{(Non-Repetitive Peak Forward Surge Current vs. Pulse Duration)}$ 

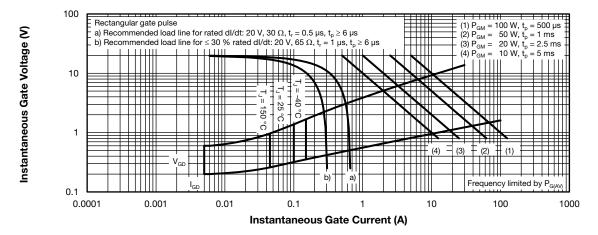


Fig. 9 - Gate Characteristics



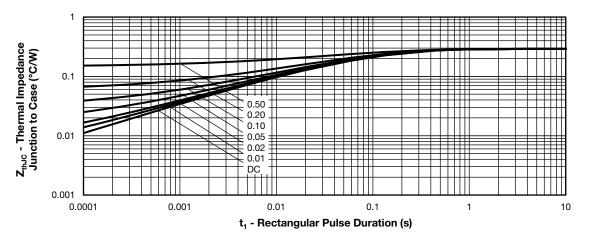
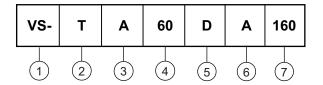


Fig. 10 -  $Z_{thJC}$  Thermal Impedance Junction to Case vs.  $t_1$  Rectangular Pulse Duration (Maximum Thermal Impedance  $Z_{thJC}$  Characteristics)

## **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Thyristor dice

Present silicon generation

4 - Rating current

Two thyristors, back to back

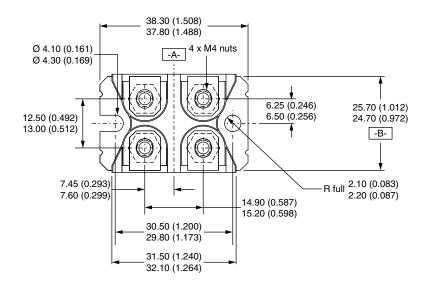
6 - Isolated SOT-227

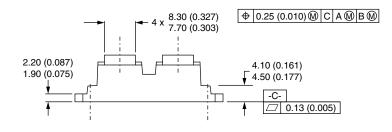
7 - Voltage rating 160 = 1600 V

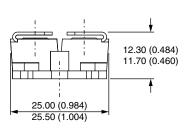
CIRCUIT CONFIGURATION							
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCU	JIT DRAWING				
Two thyristors, back to back	D	, J	Lead Assignment				

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95423			
Packaging information	www.vishay.com/doc?95425			
Application note	www.vishay.com/doc?95527			

## **DIMENSIONS** in millimeters (inches): **SOT-227 Gen 2**





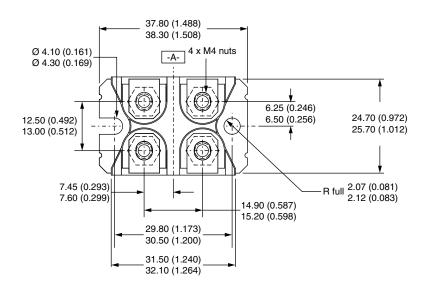


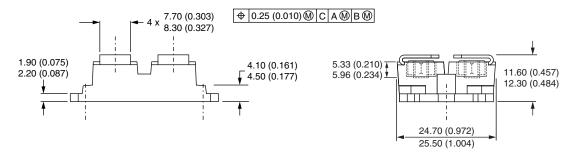
### Note

· Controlling dimension: millimeter

## SOT-227 Generation 2

## **DIMENSIONS** in millimeters (inches)





### Note

· Controlling dimension: millimeter



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